

## Article Co<sub>3</sub>O<sub>4</sub> nanopetals on Si as photoanodes for the oxidation of organics

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**Figure S1.** Linear sweep voltammetry (5mV/s) under illumination of the PETAL sample in different electrolyte solutions.



Figure S2. Mott-Schottky plots of the prepared samples in the dark and under illumination in Na<sub>2</sub>SO<sub>4</sub>.



**Figure S3.** Cyclic voltammetry performed on sample PETALS, in 0.1 M NaOH and 5 mM glucose with scan rate of 40 mV/s in the dark and with illumination.

Table S1. Sensing in Sodium Sulphate 0.1 M at 1 V vs Ag/AgCl.

	Petal	NoPetal	Hybrid
Sensibility $mA/cm^2 \times M^{-1}$	$7.5\pm0.1$	$2.4\pm0.1$	$2.4\pm0.2$
Dev.Standard ( $\mu A / cm^2$ )	0.006	0.002	0.003
LOD $(\mu M)$	$2.3\pm1.7$	$2.5\pm0.1$	$3.9\pm0.3$
$LOQ(\mu M)$	$7.7\pm0.6$	$8.4\pm0.4$	$12.9\pm1.0$
Linear Range ( $\mu M$ )	$0 \div 4$	0÷2	0÷2

	Double Layer			(	$Co_3O_4/SiO_x/Si$		$Co_3O_4$ surface states		
PETALS	R1 (Ω)	CPE-T1 (F)	CPE-α1	R2 (Ω)	CPE-T2 (F)	CPE-α2	R3 (Ω)	CPE-T3 (F)	CPE-α3
led off 0.1 V	6.7E+04	1.7E-04	0.68	3.5E+03	6.2E-08	0.90	1.9E+03	1.0E-09	0.97
led on 0.1V	4.3E+04	1.5E-04	0.85	1.6E+03	5.1E-10	1.00	5.8E+02	4.8E-07	0.64
led off 1V	3.7E+03	9.7E-05	0.87	9.2E+03	5.4E-08	0.93	2.2E+03	2.1E-09	0.92
led on 1V	4.0E+02	2.7E-03	0.63	5.8E+01	2.1E-05	0.71	1.2E+03	8.9E-10	0.99
NO PETALS	R1 (Ω)	CPE-T1 (F)	CPE-α1	R2 (Ω)	CPE-T2 (F)	CPE-α2			
led off 0.1 V	9.9E+04	5.4E-06	0.82	1.3E+03	7.0E-08	0.81			
led on 0.1V	3.7E+04	6.3E-06	0.84	1.4E+03	1.9E-07	0.74			
led off 1V	6.8E+04	4.7E-06	0.73	1.5E+04	3.3E-08	0.94			
led on 1V	3.6E+03	7.1E-06	0.82	1.1E+03	4.5E-07	0.65			
HYBRID	R1 (Ω)	CPE-T1 (F)	CPE-α1	R2 (Ω)	CPE-T2 (F)	CPE-α2			
led off 0.1 V	1.4E+04	3.6E-06	0.89	4.5E+04	1.2E-07	0.80			
led on 0.1V	5.4E+03	5.2E-06	0.88	2.1E+03	1.3E-08	0.80			
led off 1V	9.3E+03	4.0E-06	0.90	3.0E+03	5.9E-08	0.85			
led on 1V	1.2E+03	5.3E-06	0.86	1.6E+03	9.9E-09	0.81			

Table S2. Equivalent Circuit parameters.

1 The columns are ordered according to increasing frequency values; lower frequencies correspond

<sup>2</sup> to the Helmholtz layer interface, the highest frequencies correspond to the Co<sub>3</sub>O<sub>4</sub> space charge layer

<sup>3</sup> with surface states and the intermediate frequencies are assigned to the  $Co_3O_4$  SiO<sub>x</sub> interface.  $\alpha$  is the

frequency dispersion coefficient.

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